



MICROCIRCUIT DATA SHEET

CN54F821-X REV 0A0

Original Creation Date: 04/15/97
Last Update Date: 07/08/97
Last Major Revision Date: 04/15/97

10-BIT D-TYPE FLIP-FLOP

General Description

The 'F821 is a 10-bit D-type flip-flop with Tri-State true outputs arranged in a broadside pinout. The 'F821 is functionally and pin compatible with the AMD's Am29821.

Industry Part Number

54F821

NS Part Numbers

74F821DC

Prime Die

M821

Processing

Quality Conformance Inspection

Subgrp Description Temp (°C)

1	Static tests at	+25
2	Static tests at	+70
3	Static tests at	0
4	Dynamic tests at	+25
5	Dynamic tests at	+70
6	Dynamic tests at	0
7	Functional tests at	+25
8A	Functional tests at	+70
8B	Functional tests at	0
9	Switching tests at	+25
10	Switching tests at	+70
11	Switching tests at	0

Features

- TRI-STATE Outputs
- Direct replacement for AMD's Am29821

(Absolute Maximum Ratings)

(Note 1)

Storage Temperature	-65 C to +150 C
Ambient Temperature under Bias	-55 C to +125 C
Junction Temperature under Bias	-55 C to +175 C
Vcc Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30mA to +5.0mA
Voltage Applied to Output in HIGH State (with Vcc=0V)	
Standard Output	-0.5V to Vcc
TRI-STATE Output	-0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated Iol(mA)
ESD Last Passing Voltage (Min)	4000V

Note 1: Absolute Maximum ratings are those values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature Commercial	0 C to +70 C
Supply Voltage Commercial	+4.5V to +5.5V

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
DC: VCC 4.5V to 5.5V, Temp range: 0C to +70C

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
VIH	Input HIGH Voltage	Recognized as a HIGH Signal	1	INPUTS	2.0		V	1, 2, 3
VIL	Input LOW Voltage	Recognized as a LOW Signal	1	INPUTS		0.8	V	1, 2, 3
VCD	Input Clamp Diode Voltage	VCC=4.5V, IIN=-18mA	2, 3	INPUTS		-1.2	V	1, 2, 3
VOH	Output HIGH Voltage	VCC=4.5V, IOH=-1.0mA	2, 3	OUTPUTS	2.5		V	1, 2, 3
		VCC=4.5V, IOH=-3.0mA	2, 3	OUTPUTS	2.4		V	1, 2, 3
		VCC=4.75V, IOH=-1.0mA	2, 3	OUTPUTS	2.7		V	1, 2, 3
		VCC=4.75V, IOH=-3.0mA	2, 3	OUTPUTS	2.7		V	1, 2, 3
VOL	Output LOW Voltage	VCC=4.5V, IOL=24mA	2, 3	OUTPUTS		0.5	V	1, 2, 3
IIH	Input HIGH Current	VCC=5.5V, VIN=2.7V	2, 3	INPUTS		5.0	uA	1, 2, 3
IBVI	Input HIGH Current Breakdown Test	VCC=5.5V, VIN=7.0V	2, 3	INPUTS		7.0	uA	1, 2, 3
ICEX	Output HIGH Leakage Current	VCC=5.5V, VOUT = VCC	2, 3	OUTPUTS		100	uA	1, 2, 3
VID	Input Leakage Test	VCC = 0.0V, IID = 1.9uA, All other pins grounded	2, 3	INPUTS	4.75		V	1, 2, 3
IOD	Output Leakage Circuit Current	VCC = 0.0V, VIOD = 150mV, All other pins grounded	2, 3	OUTPUTS		4.75	uA	1, 2, 3
IIL	Input LOW Current	VCC=5.5V, VIN=0.5V	2, 3	INPUTS		-0.6	mA	1, 2, 3
IOZH	Output Leakage Current	VCC=5.5V, VOUT=2.7V	2, 3	OUTPUTS		50	uA	1, 2, 3
IOZL	Output Leakage Current	VCC=5.5V, VOUT=0.5V	2, 3	OUTPUTS		-50	uA	1, 2, 3
IOS	Output Short Circuit Current	VCC=5.5V, VOUT = 0V	2, 3	OUTPUTS	-60	-150	mA	1, 2, 3
ICCZ	Power Supply Current	VCC=5.5V, VO = HIGH Z	2, 3	VCC		100	mA	1, 2, 3

Electrical Characteristics

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
AC: CL=50pf, RL=500 OHMS, TR=2.5ns, TF=2.5ns SEE AC FIGS. Temp Range: 0C to +70C

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
tpLH(1)	Propagation Delay	VCC=+5.0V @ +25C, VCC=4.5V & 5.5V @ 0/+70C	2, 3	Cp to On	2.0	9.5	ns	9
			2, 3	Cp to On	2.0	10.5	ns	10, 11
tpHL(1)	Propagation Delay	VCC=+5.0V @ +25C, VCC=4.5V & 5.5V @ 0/+70C	2, 3	CP to On	2.0	9.5	ns	9
			2, 3	CP to On	2.0	10.5	ns	10, 11
tpZH	Output Enable Time	VCC=+5.0V @ +25C, VCC=4.5V & 5.5V @ 0/+70C	2, 3	OE to On	2.0	10.5	ns	9
			2, 3	OE to On	2.0	11.5	ns	10, 11
tpZL	Output Enable Time	VCC=+5.0V @ +25C, VCC=4.5V & 5.5V @ 0/+70C	2, 3	OE to On	2.0	10.5	ns	9
			2, 3	OE to On	2.0	11.5	ns	10, 11
tpHZ	Output Disable Time	VCC=+5.0V @ +25C, VCC=4.5V & 5.5V @ 0/+70C	2, 3	OE to On	1.5	7.0	ns	9
			2, 3	OE to On	1.5	7.5	ns	10, 11
tpLZ	Output Disable Time	VCC=+5.0V @ +25C, VCC=4.5V & 5.5V @ 0/+70C	2, 3	OE to On	1.5	7.0	ns	9
			2, 3	OE to On	1.5	7.5	ns	10, 11
ts (H/L)	Setup time (HIGH or LOW)	VCC=+5.0V @ +25C, VCC=4.5V & 5.5V @ 0/+70C	4	Dn to CP	2.5		ns	9
			4	Dn to CP	3.0		ns	10, 11
th (H/L)	Hold time (HIGH or LOW)	VCC=+5.0V @ +25C, VCC=4.5V & 5.5V @ 0/+70C	4	Dn to CP	2.5		ns	9, 10, 11
tw (H/L)	Pulse Width (HIGH or LOW)	VCC=+5.0V @ +25C, VCC=4.5V & 5.5V @ 0/+70C	4	CP	5.0		ns	9
			4	CP	6.0		ns	10, 11
fmax	Maximum Clock Frequency	VCC=+5.0V @ +25C, VCC=4.5V & 5.5V @ 0/+70C	4		100		MHz	9
			4		70		MHz	10, 11

Note 1: Guaranteed by applying specific input condition and testing VOL & VOH.

Note 2: Screen tested 100% on each device at +75C temperature only, subgroups A2 & A10.

Note 3: Sample tested (Method 5005, Table 1) on each MFG. lot at +75C temperature only, subgroups A2 & A10.

Note 4: Guaranteed but not tested.

Revision History

Rev	ECN #	Rel Date	Originator	Changes
0A0	M0001298	07/08/97	Linda Collins	Initial MDS Release